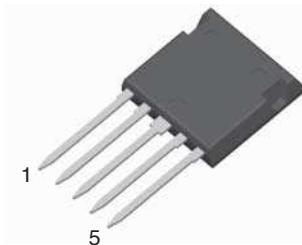
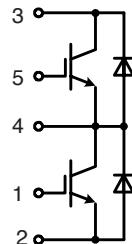


High Voltage IGBT Phase-Leg

ISOPLUS i4-PAC™ Package

FII24N170AH1

I_{C25} = 18 A
 V_{CES} = 1700 V
 $V_{CE(sat)}$ = 6.0 V



IGBT

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	1700	V	
V_{GES}	Continuous	± 20	V	
V_{GEM}	Transient	± 30	V	
I_{C25}	$T_C = 25^\circ\text{C}$	18	A	
I_{C90}	$T_C = 90^\circ\text{C}$	11	A	
I_{CM}		75	A	
RBSOA	$V_{GE} = +15 \text{ V}$; $R_G = 5 \Omega$; $T_{VJ} = 125^\circ\text{C}$ Clamped inductive load; $V_{clamp} = 1360\text{V}$	50	A	
P_c	$T_C = 25^\circ\text{C}$	140	W	

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$ unless otherwise specified)	min.	typ.
$V_{CE(sat)}$	$I_C = 16 \text{ A}$; $V_{GE} = 15 \text{ V}$ $T_{VJ} = 125^\circ\text{C}$		4.5 4.8	6.0 V V
$V_{GE(th)}$	$I_C = 250 \mu\text{A}$; $V_{GE} = V_{CE}$	3.0		5.0 V
I_{CES}	$V_{CE} = 0.8 V_{CES}$; $V_{GE} = 0 \text{ V}$ $T_{VJ} = 125^\circ\text{C}$			100 μA 1.5 mA
I_{GES}	$V_{CE} = 0 \text{ V}$; $V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$t_{d(on)}$	Inductive load $V_{CE} = 600 \text{ V}$; $I_C = 24 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$; $R_G = 39 \Omega$	48		ns
t_r		60		ns
$t_{d(off)}$		200		ns
t_f		45		ns
E_{off}		1.1		mJ
$t_{d(on)}$	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 600 \text{ V}$; $I_C = 24 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$; $R_G = 39 \Omega$	40		ns
t_r		60		ns
$t_{d(off)}$		220		ns
t_f		55		ns
E_{on}		2.5		mJ
E_{off}		1.7		mJ

Note: All characteristic values and ratings refer to a single IGBT or diode except V_{CES} , I_{CES} and C_{oes} .

Features

- NPT³ IGBT
 - low saturation voltage
 - positive temperature coefficient for easy paralleling
 - fast switching
 - short tail current for optimized performance in resonant circuits
- SONIC-FRD™ diode
 - fast reverse recovery
 - low operating forward voltage
 - low leakage current
- ISOPLUS i4-PAC™ package
 - isolated back surface
 - low coupling capacity between pins and heatsink
 - enlarged creepage towards heatsink
 - application friendly pinout
 - low inductive current path
 - high reliability
 - industry standard outline
 - UL registered, E 72873

Applications

- Single phaseleg
 - buck-boost chopper
- H-bridge
 - power supplies
 - induction heating
 - four quadrant DC drives
 - controlled rectifier
- Three phase bridge
 - AC drives
 - controlled rectifier

IGBT

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
g_{fs}	$I_C = 24 \text{ A}, V_{CE} = 10 \text{ V}$, Note 2	10	16	S
Q_g		105		nC
Q_{ge}	$I_C = 16 \text{ A}, V_{GE} = 15 \text{ V}, V_{CE} = 0.5 V_{CES}$	17		nC
Q_{gc}		30		nC
C_{ies}		2400		pF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	150		pF
C_{res}		30		pF
R_{thJC}		0.6	0.9	K/W
R_{thCK}				K/W

Diode

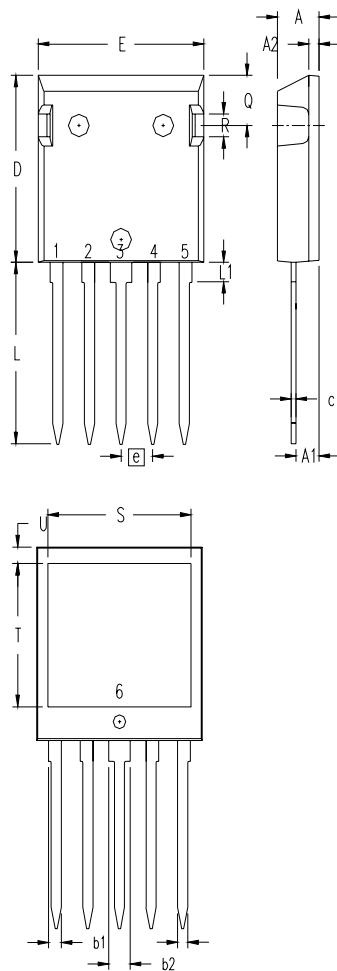
Symbol	Conditions	Maximum Ratings		
		min.	typ.	max.
I_{F25}	$T_C = 25^\circ\text{C}$	24	A	
I_{F90}	$T_C = 90^\circ\text{C}$	14	A	
Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V_F	$I_F = 20 \text{ A}$ $T_{VJ} = 125^\circ\text{C}$	2.5 2.5	2.95	V V
I_{RM}	$I_F = 20 \text{ A}; di_F/dt = -450 \text{ A}/\mu\text{s}; T_{VJ} = 125^\circ\text{C}$	23	A	
t_{rr}	$V_R = 1200 \text{ V}; V_{GE} = 0 \text{ V}$	230		ns
R_{thJC}		1.6		K/W
R_{thCS}		0.6		K/W

Component

Symbol	Conditions	Maximum Ratings		
		min.	typ.	max.
T_{VJ}		-55...+150		$^\circ\text{C}$
T_{stg}		-55...+125		$^\circ\text{C}$
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	2500		V \sim
F_c	mounting force with clip	20...120		N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
C_p	coupling capacity between shorted pins and mounting tab in the case	40		pF
d_s, d_A	pin - pin	1.7		mm
d_s, d_A	pin - backside metal	5.5		mm
Weight		9		g

IXYS MOSFETs and IGBTs are covered by 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 one or more of the following U.S. patents: 4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463

Outline Drawing

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.102	.118	2.59	3.00
A2	.046	.085	1.17	2.16
b	.045	.055	1.14	1.40
b1	.058	.068	1.47	1.73
b2	.100	.110	2.54	2.79
C	.020	.029	0.51	0.74
D	.819	.840	20.80	21.34
E	.770	.799	19.56	20.29
e	.150 BSC		3.81 BSC	
L	.780	.840	19.81	21.34
L1	.083	.102	2.11	2.59
Q	.210	.244	5.33	6.20
R	.100	.180	2.54	4.57
S	.660	.690	16.76	17.53
T	.590	.620	14.99	15.75
U	.065	.080	1.65	2.03